





#### 50V N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET IN SOT23

#### **Features and Benefits**

- BV<sub>DSS</sub> > 50V
- $R_{DS(on)} \le 3.5\Omega$  @  $V_{GS}$ = 5V
- Maximum continuous drain current I<sub>D</sub> = 200mA
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

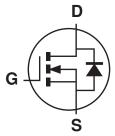
#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matt Tin Finish; Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)

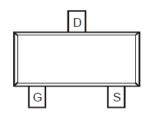
SOT-23







Device symbol



Pin-Out Top View

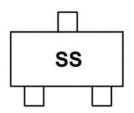
## Ordering Information (Note 3)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BSS138TA	SS	7	8	3000

Notes:

- 1. No purposefully added lead
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



SS = Product Type Marking Code





# Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	50	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	200	mA
Pulsed Drain Current (Note 5)	I <sub>DM</sub>	800	mA

# **Thermal Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 4)	PD	350	mW
Thermal Resistance, Junction to Ambient	(Note 4)	R <sub>θJA</sub>	357	°C/W
Thermal Resistance, Junction to Leads	(Note 6)	R <sub>θJL</sub>	195	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

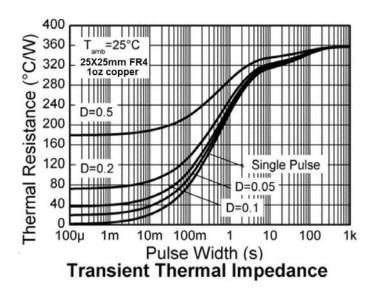
Notes:

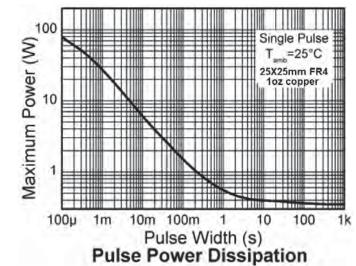
- 4. For a device mounted on 25mm X 25mm X 1.6mm FR-4 PCV with high coverage of single sided 1oz copper, in still air condition.
- 5. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.
- 6. Thermal resistance from junction to solder-point (at the end of the collector lead).

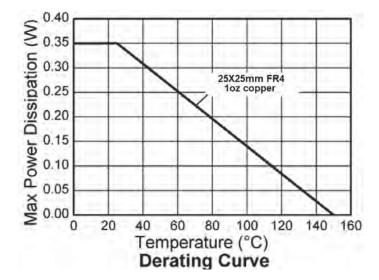




## **Thermal Characteristics**











# Electrical Characteristics @TA = 25°C unless otherwise specified

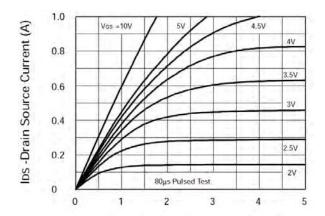
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	50	-	-	V	$V_{GS} = 0V, I_D = 0.25mA$	
				0.5	μΑ	$V_{DS} = 50V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	5	μA	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 125°C	
				100	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS						_	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.5	-	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Static Drain-Source On-Resistance (Note 7)	R <sub>DS (on)</sub>	-	-	3.5	Ω	$V_{GS} = 5V, I_D = 200mA$	
Forward Transconductance (Note 7 & 8)	9 <sub>fs</sub>	120	-	-	mS	$V_{DS} = 25V, I_D = 200mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	-	-	50	pF	V 05V V 0V	
Output Capacitance	Coss	-	-	25	pF	$V_{DS} = 25V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	-	8	pF		
Turn-On Delay Time (Note 9)	t <sub>D(on)</sub>	-	10	-	ns		
Turn-On Rise Time (Note 9)	t <sub>r</sub>	-	10	-	ns	V <sub>DD</sub> = 30V, I <sub>D</sub> = 280mA	
Turn-Off Delay Time (Note 9)	t <sub>D(off)</sub>	-	15	-	ns		
Turn-Off Fall Time (Note 9)	t <sub>f</sub>	-	25	-	ns		

Notes:

- 7. Measured under pulsed conditions. Width = 300µs. Duty cycle ≤ 2%.
- Sample test.
- 9. Switching times measured with  $50\Omega$  source impedance and <5ns rise time on a pulse generator.

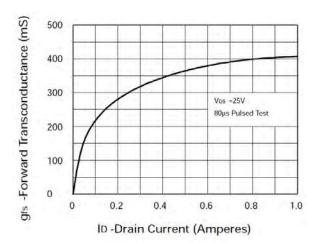


## **Electrical Characteristics**



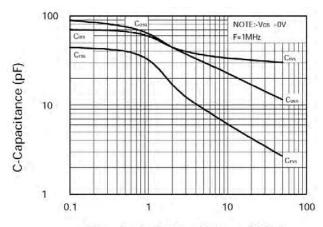
VDS -Drain Source Voltage (Volts)

### **Saturation Characteristics**



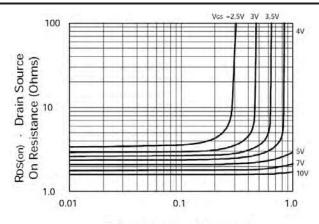
Typical Transconductance vs.

Drain Current



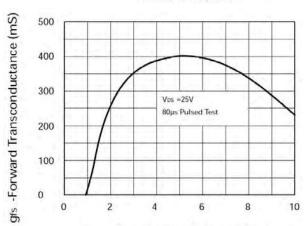
VDS -Drain Source Voltage (Volts)

Typical Capacitance vs. Drain - Source Voltage



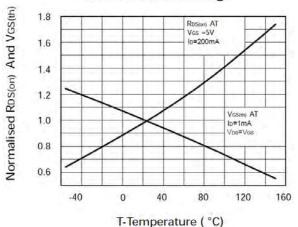
**ID-Drain Current (Amperes)** 

# Typical On Resistance vs. Drain Current



VGS -Gate Source Voltage (Volts)

# Typical Transconductance vs. Gate - Source Voltage

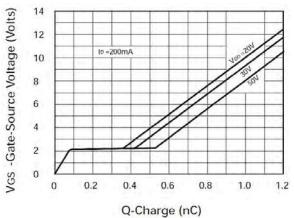


Normalised RDS(on) And VGS(th) vs. Temperature





# **Electrical Characteristics – (Continuous)**



Typical Gate Charge vs. Gate-Source Voltage

80µs Pulsed Test

1.0

0.9

0.8 0.7 0.6 0.5 0.4 0.3

100µA

1mA

VSD - Source Drain Voltage (V)



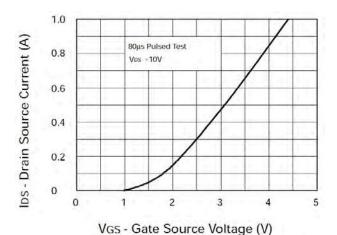
1A

**Typical Diode Forward Voltage** 

10mA

IDS - Drain Source Current

100mA

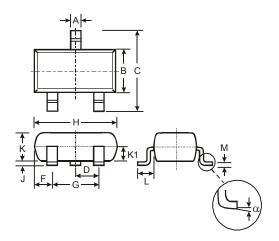


**Typical Transfer Characteristics** 



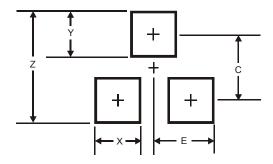


# **Package Outline Dimensions**



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	1	1	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35





#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

#### **LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com